## EE-557 Semiconductor devices I

Matioli Elison

| Cursus | Sem. | Type |
| :--- | :--- | :--- |
| Electrical and Electronical Engineering | MA1, MA3 | Obl. |
| Energy Science and Technology | MA1, MA3 | Opt. |
| MNIS | MA3 | Opt. |
| Minor in Quantum Science and Engineering | H | Opt. |
| Quantum Science and Engineering | MA1, MA3 | Opt. |


| Language of <br> teaching <br> Credits | English |
| :--- | :--- |
| Session | 4 |
| Semester | Winter |
| Exam | Fall |
| Workload the | semester |
| Weeks | 120 h |
| Hours | $\mathbf{4}$ weekly |
| $\quad$Lecture <br> Exercises | 3 weekly |
| Number of |  |
| positions |  |

## Summary

This course aims to give a solid introduction to semiconductors, from Silicon to compound semiconductors, making the connection between the physics and their application in real life. We will explore several experimental techniques related to current semiconductor research and development.

## Content

1. Introduction to Semiconductor Physics
2. Carrier Generation and Recombination

- link to LEDs and Solar cells

3. Charge Transport

- Hall measurements

4. Non-uniformly doped semiconductors

- Schokley equations.

5. p-n junctions
6. Metal semiconductor junctions

- Schottky and Ohmic junctions

7. Metal Oxide Semiconductor MOSFETs
8. Semiconductor junctions (Compound semiconductors)

- Band structure simulations

9. Semiconductor devices of today

- High electron mobility transistors (HEMTs)
- Power transistors


## Keywords

Semiconductors, compound, Silicon, GaAs, GaN, transistors, LEDs, solar cells, HEMTs

## Learning Prerequisites

Recommended courses

Physique général III et IV, Electronique I et II

## Teaching methods

Lectures
Assignments
Lab sessions
Simulations

## Assessment methods

homeworks, mid-term and final exams

## Resources

## Ressources en bibliothèque

- Integrated microelectronic devices : physics and modeling /del Alamo


## Notes/Handbook

Notes and slides will be published on moodle after each lecture

## Moodle Link

- https://go.epfl.ch/EE-557

